Supplementary Material: Pressure-Tunable Large Anomalous Hall

Effect in Ferromagnetic Metal LiMn₆Sn₆

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Fig. S1. Physical properties of LiMn₆Sn₆ single crystals. (a) Temperature dependence of resistivity with current along *a* axis. (b) Temperature dependence of the magnetization under magnetic field of H = 100 Oe lying in and perpendicular to the *ab* plane. (c) The isothermal magnetization at T = 2 K for H // ab and H // c.



Fig. S2. (a)-(d) Field dependence of magnetoresistance (MR) at various temperatures and selected pressures in Run-2.



Fig. S3. (a)-(d) Field dependence of Hall resistivity ρ_{yx} at various temperature and selected pressures in Run-2.